

# OKI electronic components

## KGF2511

Midium Power Amplifier for UHF band

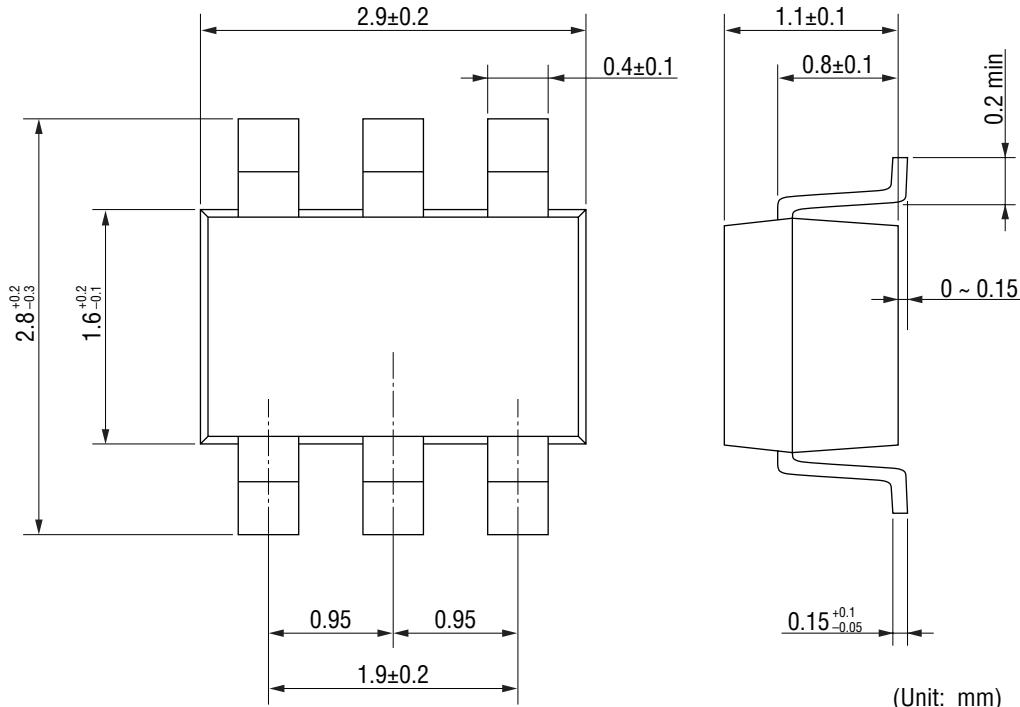
### GENERAL DESCRIPTION

The KGF2511 is a midium power amplifier for UHF band that features high output power, high linear gain, low distortion and low-current dissipation. The KGF2511 has specifications guaranteed by fixed matching circuit of 2.8V and 900MHz band, although external impedance matching circuits are required. Because of the high output power and low distortion at the low operating current, the KGF2511 is ideal as a transmitter driver stage amplifire for portable phones such as PDC and CDMA.

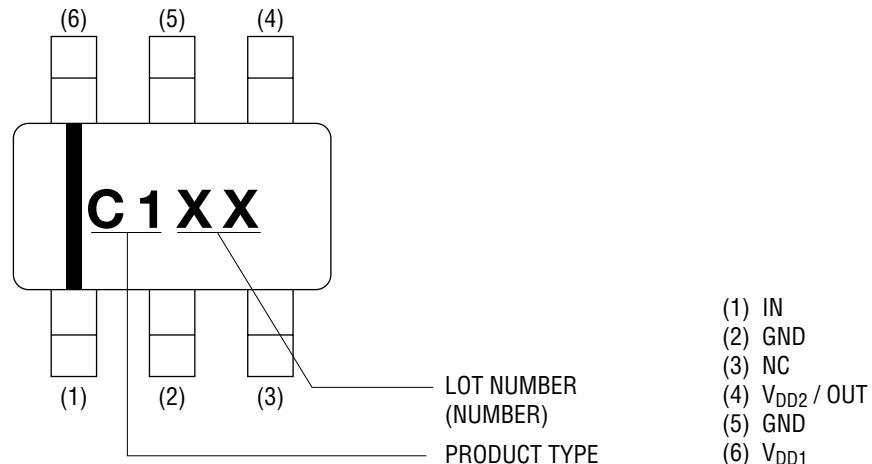
### FEATURES

- High output power: 8dBm (min)
- High linear gain: 27dB (min)
- Low distortion (ACP): -55dBC (max) @ $P_O=8\text{dBm}$ ,  $\pi/4\text{DQPSK}$ ,  $\pm 50\text{kHz}$
- Low voltage and Low current operation: 2.8V, 28mA (max)
- Self-bias circuit configuration with built-in source capacitor
- Surface mount 6-pin SOP plastic package

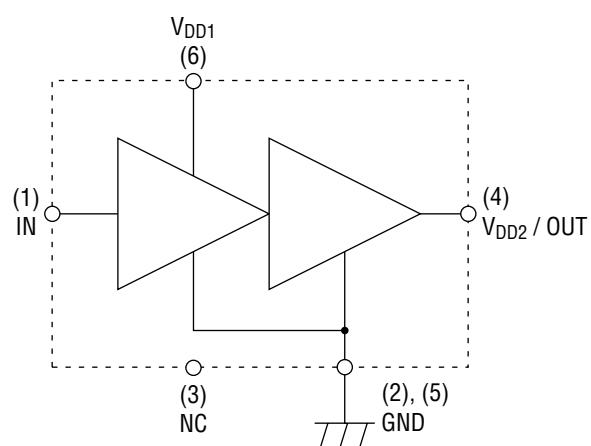
### OUTLINE DIMENSIONS



## MARKING



## CIRCUIT



**ABSOLUTE MAXIMUM RATINGS**

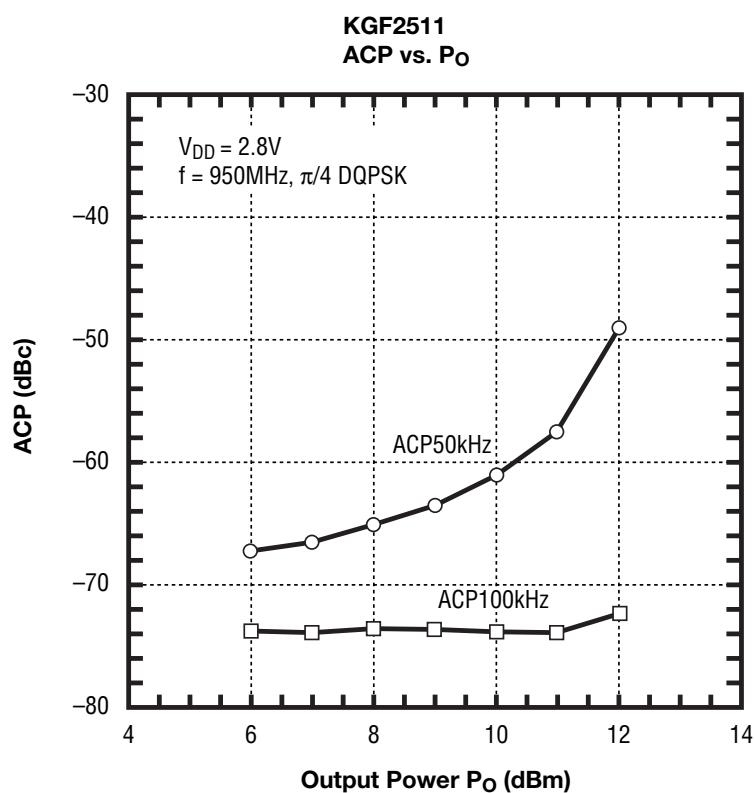
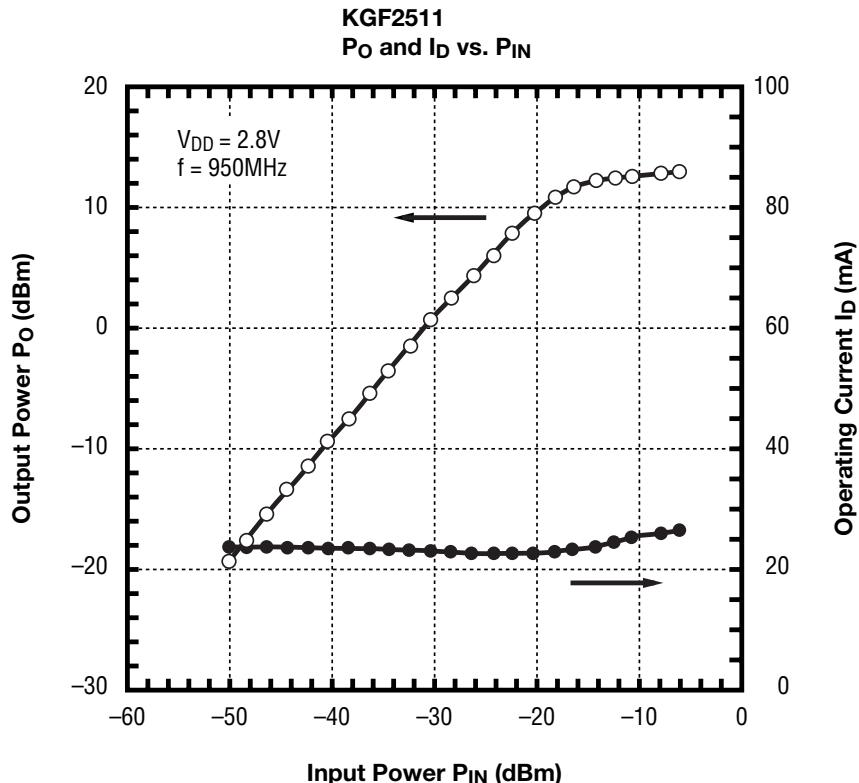
<b>Item</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Unit</b>	<b>Min.</b>	<b>Max.</b>
Supply Voltage	$V_{DD}$	$T_a = 25^\circ C$	V	—	7
Total power dissipation	$P_{TOT}$	$T_a = 25^\circ C$	mW	—	300
Operating temperature	$T_{OPE}$	—	$^\circ C$	-35	+85
Storage temperature	$T_{STG}$	—	$^\circ C$	-45	+125

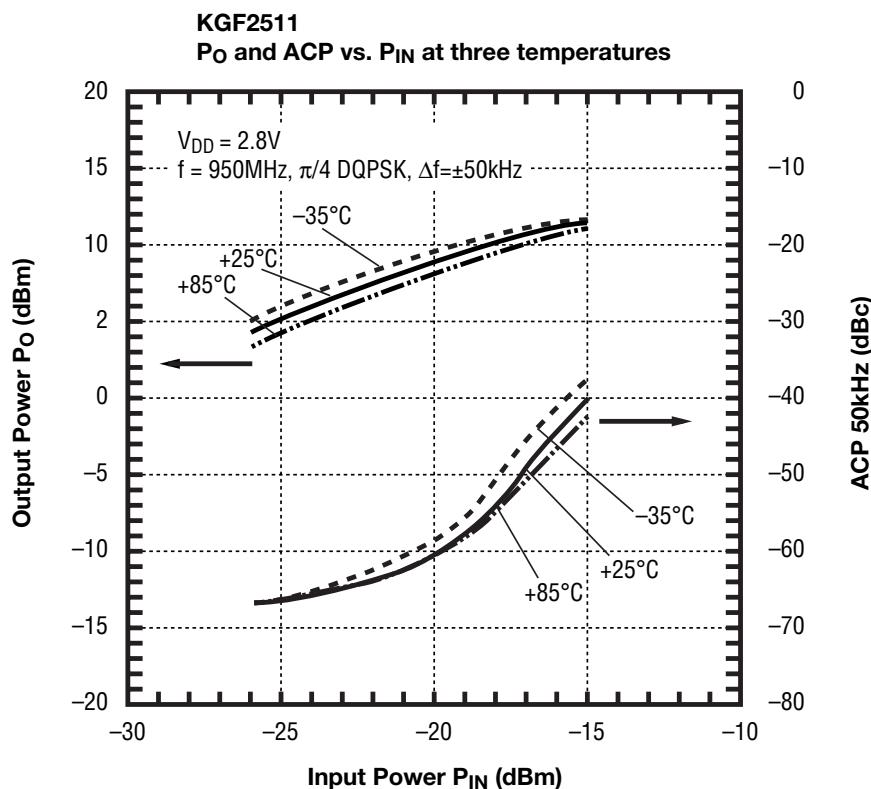
**ELECTRICAL CHARACTERISTICS**

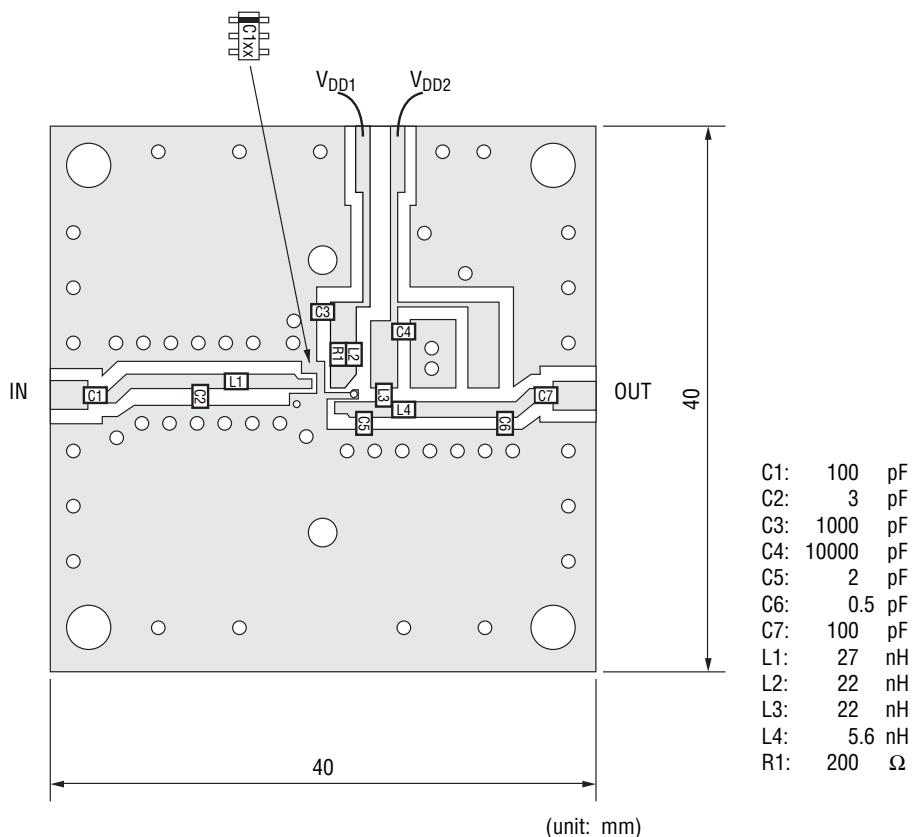
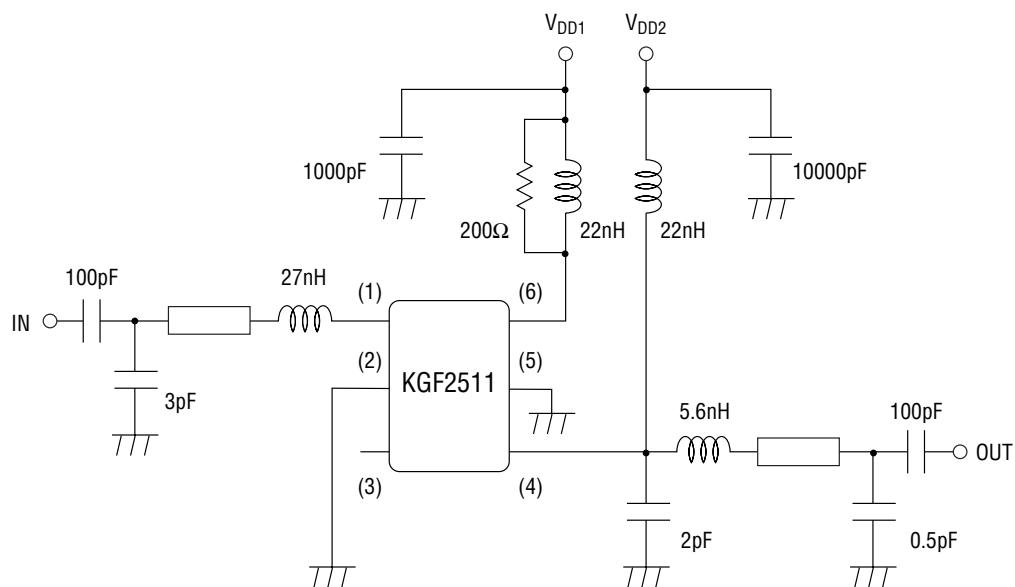
(Ta = 25°C)

<b>Item</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Unit</b>	<b>Min.</b>	<b>Typ.</b>	<b>Max.</b>
Frequency	f	—	MHz	889	—	960
Operating current	$I_{DD}$	(*1), $P_{IN} = -20$ dBm	mA	—	24	28
Linear Gain	$G_{LIN}$	(*1), $P_{IN} = -30$ dBm	dB	27	30	—
Output Power	$P_0$	(*1), $P_{IN} = -20$ dBm	dBm	8	10	—
Adjacent channel power 1	ACP1	(*1), $P_0 = 8$ dBm ±50 kHz offset	dBc	—	-60	-55
Adjacent channel power 2	ACP2	(*1), $P_0 = 8$ dBm ±100 kHz offset	dBc	—	-70	-65

\*1 Self-bias condition:  $V_{DD} = 2.8$  V,  $\pi/4$  DQPSK







Substrate: Teflon-fiberglass  
 (0.8mm<sup>t</sup>, 18μm<sup>t</sup> Cu plated both side, ε<sub>r</sub> = 2.6)